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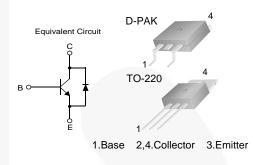
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KSC5502D / KSC5502DT NPN Triple Diffused Planar Silicon Transistor

Features

- High Voltage Power Switch Switching Application
- Wide Safe Operating Area
- Built-in Free-Wheeling Diode
- Suitable for Electronic Ballast Application
- Small Variance in Storage Time
- Two Package Choices : D-PAK or TO-220



Ordering Information

Part Number	Top Mark	Package	Packing Method
KSC5502DTM	C5502D	TO-252 3L (DPAK)	Tape and Reel
KSC5502DTTU	C5502D	TO-220 3L	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_c = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	1200	V
V _{CEO}	Collector-Emitter Voltage	600	V
V _{EBO}	Emitter-Base Voltage	12	V
۱ _C	Collector Current (DC)	2	A
I _{CP}	Collector Current (Pulse) ⁽¹⁾	4	A
Ι _Β	Base Current (DC)	1	Α
I _{BP}	Base Current (Pulse) ⁽¹⁾	2	Α
ТJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	-65 to 150	°C
EAS	Avalanche Energy (T _J = 25°C)	2.5	mJ

Note:

1. Pulse test: Pulse width = 5 ms, duty cycle \leq 10%.

July 2014

Thermal Characteristics

Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	KSC5502D (D-PAK)	KSC5502DT (TO-220)	Unit
P _C	Collector Dissipation ($T_C = 25^{\circ}C$)	87.83	118.16	W
R _{θJC}	Thermal Resistance, Junction to Case	1.42 1.06		°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	111.0 62.5		°C/W
TL	Maximum Lead Temperature for Soldering Purpose: 1/8 inch from Case for 5 seconds	270		°C

Electrical Characteristics

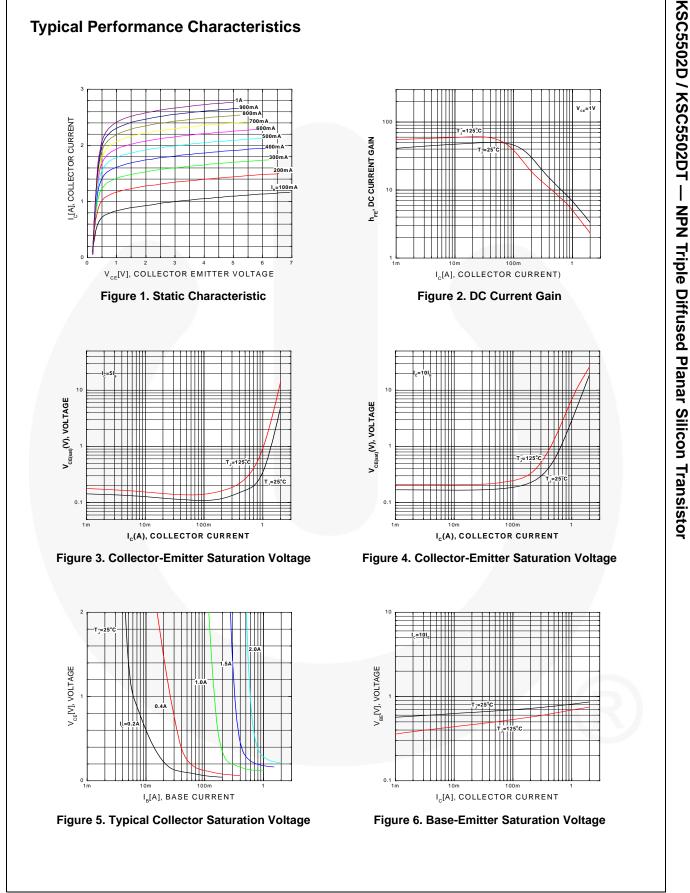
Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

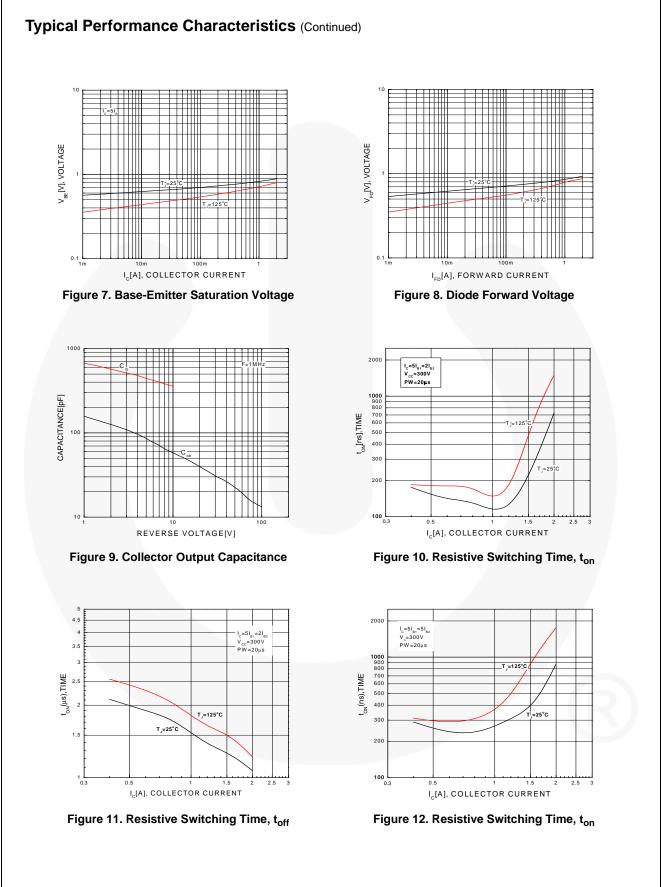
Symbol	Parameter	Conditions I _C = 1 mA, I _E = 0		Min.	Тур.	Max.	Uni
BV _{CBO}	Collector-Base Breakdown Voltage			1200	1350		V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 5 \text{ mA}, I_{\rm B} = 0$		600	750		V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 500 \ \mu A, I_{C} = 0$		12.0	13.7		V
	Collector Cut off Current	$\lambda = 1200 \lambda \lambda = 0$	$T_C = 25^{\circ}C$			100	
ICES	Collector Cut-off Current	$V_{CES} = 1200 V, V_{BE} = 0$	T _C = 125°C			500	μA
	Collector Cut-off Current	V _{CF} = 600 V, I _B = 0	$T_C = 25^{\circ}C$			100	- μΑ
ICEO	Collector Cut-on Cutterit	$v_{CE} = 600 v, I_B = 0$	T _C = 125°C			500	
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 12 \text{ V}, \text{ I}_{C} = 0$	$T_C = 25^{\circ}C$			10	μA
		V _{CF} = 1 V, I _C = 0.2 A	T _C = 25°C	15	28	40	
		$v_{CE} = 1 v, t_{C} = 0.2 A$	T _C = 125°C	8	18		
h	DC Current Gain	$V_{CE} = 1 \text{ V}, I_{C} = 1 \text{ A}$	$T_C = 25^{\circ}C$	4.0	6.4		
h _{FE}		$v_{CE} = 1$ v, $i_C = 1$ A	T _C = 125°C	3.0	4.7		
		V _{CE} = 2.5 V,	$T_C = 25^{\circ}C$	12	20	30	
		$I_{\rm C} = 0.5 \rm{A}$	T _C = 125°C	6	12		
	Collector-Emitter Saturation Voltage	$I_{\rm C} = 0.2 \text{ A}, I_{\rm B} = 0.02 \text{ A}$	$T_C = 25^{\circ}C$		0.31	0.80	- V
			$T_{C} = 125^{\circ}C$		0.54	1.10	
V (cot)		$I_{\rm C} = 0.4$ A, $I_{\rm B} = 0.08$ A	$T_C = 25^{\circ}C$		0.15	0.60	
V _{CE} (sat)			T _C = 125°C		0.23	1.00	
		$ _{0} - 1 \Delta _{0} - 02 \Delta _{0}$	T _C = 25°C		0.40	1.50	
			T _C = 125°C		1.30	3.00	
		$I_{\rm C} = 0.4$ A, $I_{\rm B} = 0.08$ A	$T_C = 25^{\circ}C$		0.77	1.00	
V (aat)	Base-Emitter Saturation Voltage		T _C = 125°C		0.60	0.90	V
V _{BE} (sat)	Base-Emilier Saturation voltage		$T_C = 25^{\circ}C$		0.83	1.20	
		I _C = 1 A, I _B = 0.2 A	$T_{C} = 125^{\circ}C$		0.70	1.00	
C _{ib}	Input Capacitance	$V_{EB} = 8 V, I_{C} = 0, f = 1$	MHz		385	500	pF
C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0, f = 10 \text{ V}$	1 MHz		60	100	pF
f _T	Current Gain Bandwidth Product	I _C = 0.5 A,V _{CE} = 10 V			11		MH
		I _F = 0.2 A	$T_C = 25^{\circ}C$		0.75	1.20	
	Diode Forward Voltage		T _C = 125°C		0.59		V
V _F		I _F = 0.4 A	$T_C = 25^{\circ}C$		0.80	1.30	
			T _C = 125°C		0.64		
		I _F = 1 A	T _C = 25°C		0.90	1.50	1

Electrical Characteristics

Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions		Min	Тур.	Max.	Unit	
		I _F = 0.2 A			650			
t _{fr}	Diode Froward Recovery Time (di/dt=10 A/μs)	I _F = 0.4 A			740		ns	
		I _F = 1 A			785			
		I _C = 0.4 A, I _{B1} = 80 mA,	at 1 µs		7.2		V	
		$V_{CC} = 300 V$	at 3 µs		1.8			
VCE(DSAT)	Dynamic Saturation Voltage	I _C = 1 A, I _{B1} = 200 mA,	at 1 µs		18.0			
		$V_{CC} = 300 V$	at 3 µs		6.0			
Resistive L	oad Switching (D.C < 10%, P	ulse Width = 20 s)						
+	Turn-On Time		$T_C = 25^{\circ}C$		175	350	ns	
t _{ON}	Turn-On Time	$I_{C} = 0.4 \text{ A}, I_{B1} = 80 \text{ mA},$ $I_{B2} = 0.2 \text{ A}, V_{CC} = 300 \text{ V},$	T _C = 125°C		185			
+	Turn-Off Time	$R_1 = 750 \Omega$	$T_C = 25^{\circ}C$		2.1	3.0	μs	
tOFF			T _C = 125°C		2.6			
+	Turn-On Time	I _C = 1 A, I _{B1} = 160 mA,	T _C = 25°C		240	450	- ns	
ton	Tum-On Time	$I_{B2} = 160 \text{ mA},$ $V_{CC} = 300 \text{ V},$	$T_{C} = 125^{\circ}C$		310			
to	Turn-Off Time		$T_C = 25^{\circ}C$		3.7	5.0		
tOFF		$R_L = 300 \Omega$	$T_{C} = 125^{\circ}C$		4.5		μs	
Inductive L	oad Switching (V _{CC} = 15 V)							
tama	Storage Time		$T_C = 25^{\circ}C$		1.2	2.0	0μs	
t _{STG}	olorage nine		$T_{C} = 125^{\circ}C$		1.5			
t _F	Fall Time	I _C = 0.4 A, I _{B1} = 80 mA, I _{B2} = 0.2 A, V _Z = 300 V,	$T_C = 25^{\circ}C$		90	200	ne	
۲F		$L_{\rm C} = 200 \text{H}$	$T_{C} = 125^{\circ}C$		65		ns	
to	Cross-Over Time	°	$T_C = 25^{\circ}C$		185	350	ns	
t _C	Closs-Over Time		$T_{C} = 125^{\circ}C$		145		115	
tana	Storage Time		$T_C = 25^{\circ}C$		3.30	4.50	μs	
t _{STG}		I _C = 0.8 A, I _{B1} = 160 mA,	$T_{C} = 125^{\circ}C$		3.75			
t_	Fall Time	I _{B2} = 160 mA,	$T_C = 25^{\circ}C$		90	250	ns	
t _F		$V_{\rm CC} = 300 \rm V,$	T _C = 125°C		160		115	
ta	Cross-over Time	L _C = 200 H	$T_C = 25^{\circ}C$		300	600	ns	
t _C		$T_{\rm C} = 125^{\circ}{\rm C}$			570		115	

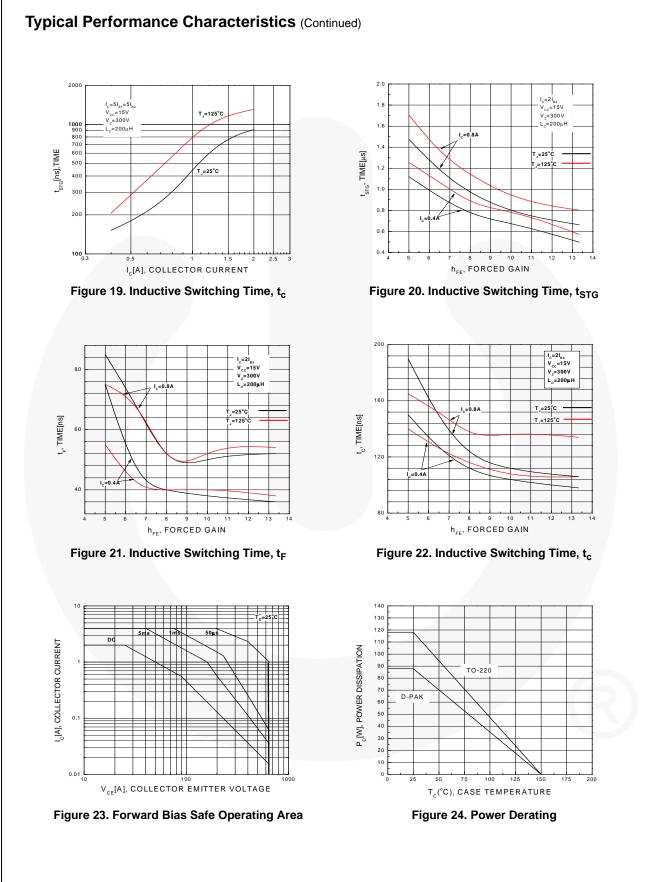


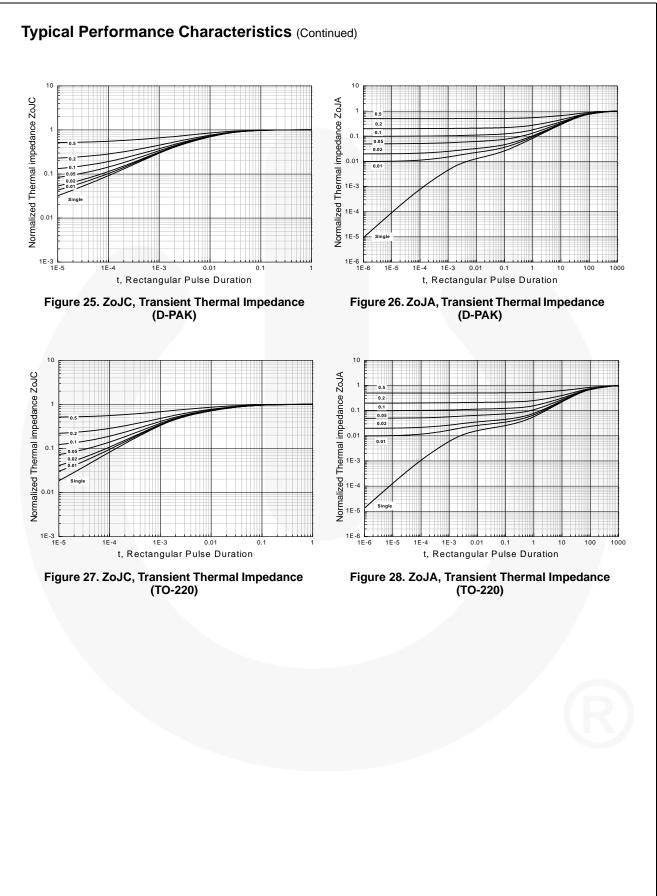


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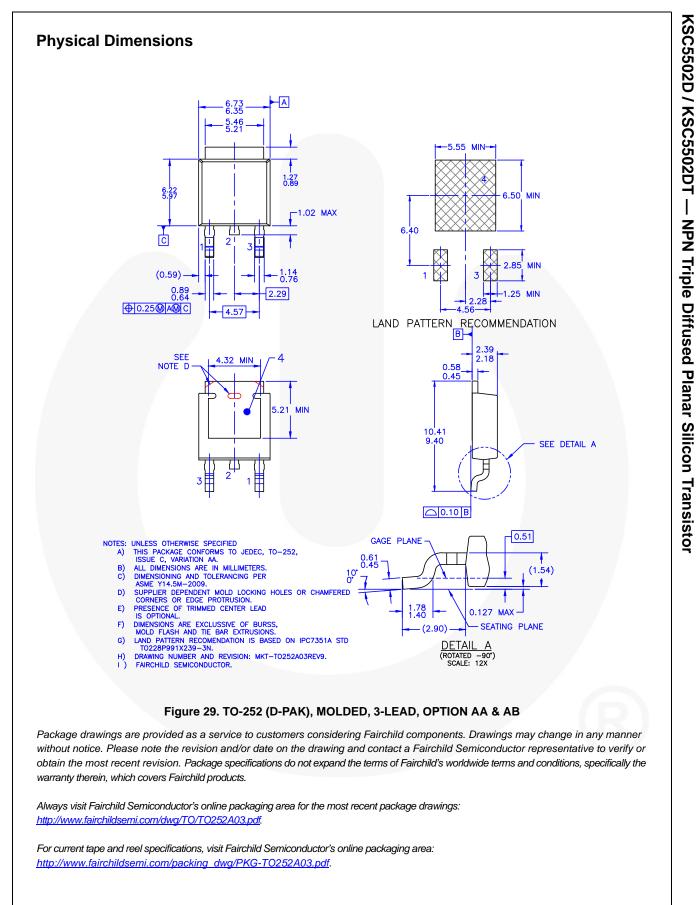
6.5 I_c=5I_{B1}=2I_{B2} V_{cc}=15V V_z=300V I_c=5I_{B1}=5I_{B2} V_=300V 2.5 5.5 e^c PW =20μs L_c=200µH 5 4.5 $t_{STG}(\mu s), TIME$ t_{ov}(µs),TIME -125 3.5 T_=25°C т_=25°С 2.5 2 L 0.3 0.3 2.5 2.5 1.5 3 Ic[A], COLLECTOR CURRENT I_[A], COLLECTOR CURRENT Figure 13. Resistive Switching Time, toff Figure 14. Inductive Switching Time, t_{STG} 110 600 550 $I_{c}=5I_{B1}=2I_{B2}$ $V_{cc}=15V$ $V_{z}=300V$ $L_{c}=200\mu H$ 100 - I_c=5I_{B1}=2I_B V_{cc}=15V V_z=300V L_c=200μH 500 450 90 400 350 80 300 T ;=12 t_F(ns),TIME t_c[ns], TIME 70 T_=125°C 250 60 200 =25 50 150 40 100 0.5 1.5 2.5 I_C[A], COLLECTOR CURRENT I_C[A], COLLECTOR CURRENT Figure 16. Inductive Switching Time, t_c Figure 15. Inductive Switching Time, t_F 1000 900 800 700 600 $I_c = 5I_{B_1} = 5I_{B_2}$ $V_{cc} = 15V$ $V_z = 300V$ $L_c = 200 \mu H$ $I_{c}=5I_{B1}=5I_{B2}$ $V_{cc}=15V$ $V_{z}=300V$ $L_{c}=200\mu$ H 4.5 500 T =125°C 400 T_=125° 3. t_{srg}[µs],TIME 300 t_F[ns],TIME T_=25°C 200 T_=25° 2.5 100 90 80 70 60 50 2 L 1.5 2.5 1.5 2.5 0.5 I_c[A], COLLECTOR CURRENT I_c[A], COLLECTOR CURRENT Figure 17. Inductive Switching Time, t_{STG} Figure 18. Inductive Switching Time, t_F

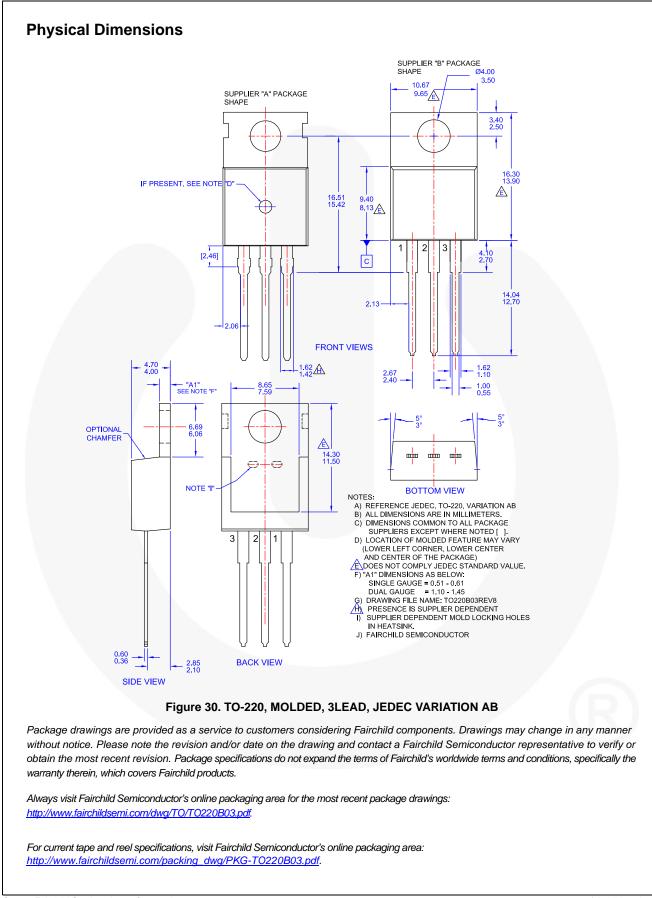
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